



M T B F

(E I A J R C R - 9 1 0 2)

Model	MGFS80483R3
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	6	0.2110	
2		Hybrid	0	0.0000	
3	Transistors		6	0.3982	
4	Diodes		18	0.3220	
5	LED•Optocouplers		2	0.1400	
6	Resistors		77	0.3375	
7	Capacitors		56	0.4144	
8	Transformer•Choke Coil		4	0.0920	
9	Connectors		399	0.0549	
10	Others		2	0.2200	
Total Failure Rate [10 ⁻⁶ /H]				2.1900	

M T B F	[H]	457,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—